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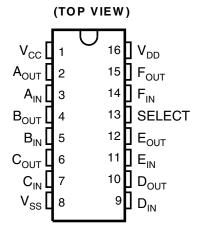
CMOS HEX VOLTAGE-LEVEL SHIFTER FOR TTL-TO-CMOS or CMOS-TO-CMOS OPERATION

FEATURES

- Independence of Power-Supply Sequence Considerations – V_{CC} Can Exceed V_{DD}; Input Signals Can Exceed Both V_{CC} and V_{DD}
- Up and Down Level-Shifting Capability
- Shiftable Input Threshold for Either CMOS or TTL Compatibility
- Standardized Symmetrical Output Characteristics
- 100% Tested for Quiescent Current at 20 V
- Maximum Input Current of 1 μA at 18 V Over Full Package-Temperature Range: 100 nA at 18 V and 25°C
- 5 V, 10 V, and 15 V Parametric Ratings
- Meets All Requirements of JEDEC Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

SUPPORTS DEFENSE, AEROSPACE, AND MEDICAL APPLICATIONS

- Controlled Baseline
- One Assembly/Test Site
- One Fabrication Site
- Available in Military (-55°C/125°C)
 Temperature Range⁽¹⁾
- Extended Product Life Cycle
- Extended Product-Change Notification
- Product Traceability



(1) Additional temperature ranges are available - contact factory

DESCRIPTION

CD4504B hex voltage level-shifter consists of six circuits which shift input signals from the V_{CC} logic level to the V_{DD} logic level. To shift TTL signals to CMOS logic levels, the SELECT input is at the V_{CC} HIGH logic state. When the SELECT input is at a LOW logic state, each circuit translates signals from one CMOS level to another.

ORDERING INFORMATION(1)

T _A	PAC	KAGE ⁽²⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
-55°C to 125°C	TSSOP - PW	Reel of 2000	CD4504BMPWREP	4504BEP

⁽¹⁾ Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

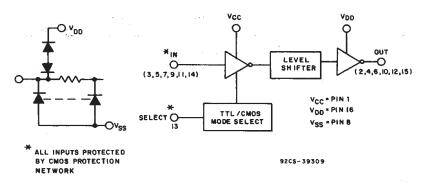


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

⁽²⁾ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.



FUNCTIONAL BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{DD}	DC supply-voltage range, voltages referenced to V _{SS} terminate	al	-0.5	+20	V
	Input voltage range, all inputs		-0.5	V _{CC} + 0.5	V
	DC input current, any one input				
		$T_A = -55^{\circ}C \text{ to } +100^{\circ}C$		500	mW
P _D	Power dissipation per package	T _A = +100°C to +125°C	Derate Line	early at 12 m	W/°C to
	Device dissipation per output transistor, for TA = full package-temperature range (all package types)			100	mW
T _A	Operating temperature range		- 55	+125	°C
θ_{JA}	Package thermal impedance ⁽¹⁾			91.1	°C/W
T _{stg}	Storage temperature range		-85	+150	°C
	Lead temperature (during soldering), at distance $1/16 \pm 1/32$ 10 s max	inch (1.59 \pm 0.79 mm) from case for		+265	°C

⁽¹⁾ The package thermal impedance is calculated in accordance with JESD 51-7.

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STATIC ELECTRICAL CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

			CONDI	TIONS		LIN	IITS AT	INDICA	TED TEI	MPERA	TURES (°C)		
CHARAC	CTERISTIC	Vo	V _{IN}	V _{CC}	V _{CC}		40	. 05	.405		+25		UNIT	
			(V)	(V)	(V)	–55	-40	+85	+125	MIN	TYP	MAX		
			0, 5	5	5	1.5	1.5	1.5	1.5		0.02	1.5	mA	
Quiescent device of	urrent,		0, 10	5	10	2	2	2	2		0.02	2	mA	
$\rm I_{\rm DD}$ max and $\rm I_{\rm CC}$ in	CMOS-CMOS mode		0, 15	5	15	4	4	120	120		0.02	4	^	
			0, 20	5	20	20	20	600	600		0.04	20	μΑ	
			0, 5	5	5	5	5	6	6		2.5	5		
Quiescent device of I _{CC} max TTL-CMO			0, 10	5	10	5	5	6	6		2.5	5	mΑ	
ICC Max 115-0MO	5 mode		0, 15	5	15	5	5	6	6		2.5	5		
		0.4	0, 5		5	0.64	0.61	0.42	0.36	0.51	1			
Output low (sink) c I _{OL} min	urrent,	0.5	0, 10		10	1.6	1.5	1.1	0.9	1.3	2.6			
IOF IIIII		1.5	0, 15		15	4.2	4	2.8	2.4	3.4	6.8			
Output high (source) current, I _{OH} min		4.6	0, 5		5	-0.64	-0.61	-0.42	-0.36	-0.51	-1		mA	
		2.5	0, 5		5	-2	-1.8	-1.3	-1.15	-1.6	-3.2			
		9.5	0, 10		10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6			
		13.5	0, 15		15	-4.2	-4	-2.8	-2.4	-3.4	-6.8			
			0, 5		5	0.05 0.05				0	0.05			
Output voltage: low-level, V _{OL} max			0, 10		10						0	0.05	1	
iow ievei, vol max			0, 15		15		0.	05			0	0.05		
			0, 5		5		4.	95		4.95	5			
Output voltage: high-level, V _{OH} min			0, 10		10		9.	95		9.95	10			
riigii-ievei, von iiiii	ı		0, 15		15		14	.95		14.95	15			
	TTL-CMOS	1		5	10		0	.8				0.8		
	TTL-CMOS	1		5	15		0	.8				0.8	.,	
Input low voltage, V _{IL} max ⁽¹⁾	CMOS-CMOS	1		5	10		1	.5				1.5	V	
VIL Max	CMOS-CMOS	1.5		5	15		1	.5				1.5		
	CMOS-CMOS	1.5		10	15		;	3				3		
	TTL-CMOS	9		5	10			2		2			=	
	TTL-CMOS	13.5		5	15			2		2			1	
Input high voltage, V _{IH} min ⁽¹⁾	CMOS-CMOS	9		5	10		3	.5		3.5			1	
AIH IIIIII	CMOS-CMOS	13.5		5	15		3	.5		3.5			1	
	CMOS-CMOS	13.5		10	15		•	7		7			1	
Input current, I _{IN} m	ax		0, 18		18	±0.1	±0.1	±1	±1		±10 ⁻⁵	±0.1	μΑ	

⁽¹⁾ Applies to the six input signals. For mode control (P13), only the CMOS-CMOS ratings apply.

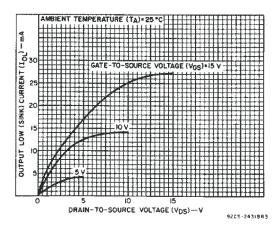


Figure 1. Typical Output Low (sink) Current Characteristics

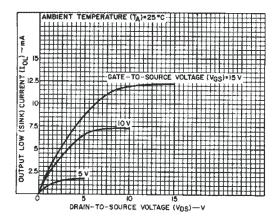


Figure 2. Minimum Output Low (sink) Current Characteristics

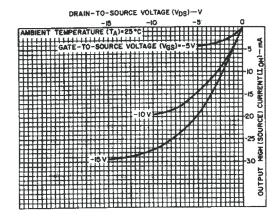


Figure 3. Typical Output High (source) Current Characteristics

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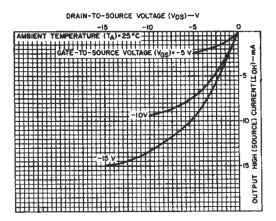


Figure 4. Minimum Output High (source) Current Characteristics

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RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

	CHARACTERISTIC	MIN	MAX	UNIT
V_{DD}	Supply-voltage range (for T _A = full package temperature range)	5	18	V

DYNAMIC ELECTRICAL CHARACTERISTICS

 $T_{A}=25^{\circ}C,\ Input\ t_{r},t_{f}=20\ ns,\ C_{L}=50\ pF,\ R_{L}=200\ \Omega$

	CHARACTERISTIC	SHIFTING MODE	V _{CC}	V_{DD}	LIMI	UNIT		
	CHARACTERISTIC	SHIFTING MODE	(V)	(V)	TYP MAX		ONII	
		TTL to CMOS	5	10	140	280		
		$V_{DD} > V_{CC}$	5	15	140	280		
			5	10	120	240		
	Decreasion deleve high to leve	CMOS to CMOS V _{DD} > V _{CC}	5	15	120	240		
t _{PHL}	Propagation delay: high-to-low,	VDD > VCC	10	15	70	140	ns	
			10	5	275	550		
		CMOS to CMOS V _{CC} > V _{DD}	15	5	275	550		
		VCC > VDD	15	10	70	140		
		TTL to CMOS	5	10	140	280		
	Propagation delay: low-to-high	$V_{DD} > V_{CC}$	5	15	140	280	ns	
			5	10	120	240		
		CMOS to CMOS V _{DD} > V _{CC}	5	15	120	240		
t _{PLH}		ADD > AGC	10	15	70	140		
			10	5	200	400		
		CMOS to CMOS $V_{CC} > V_{DD}$	15	5	200	400		
		, CC > , OD	15	10	60	120		
				5	100	200		
t _{THL} , t _{TLH}	Transition time	All modes		10	50	100	ns	
				15	40	80		
C _{IN}	Input capacitance	Any input			5	7.5	pF	

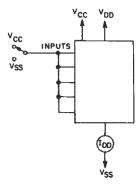


Figure 5. Quiescent Device Current

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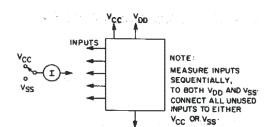


Figure 6. Input Current

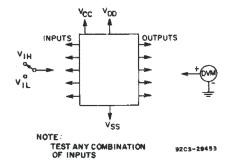


Figure 7. Input Voltage

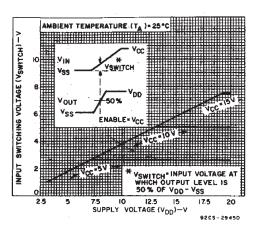


Figure 8. Typical Input Switching as a Function of High-Level Supply Voltage (SELECT at V_{CC} – CMOS Mode

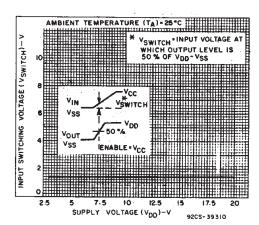


Figure 9. Typical Input Switching as a Function of High-Level Supply Voltage (SELECT at $V_{\rm SS}$ – TTL Mode)

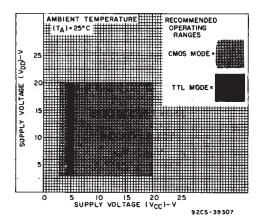
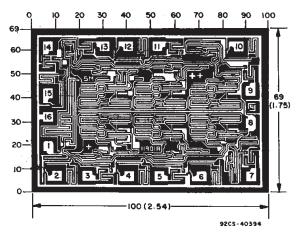


Figure 10. High-Level Supply Voltage vs. Low-Level Supply Voltage



A. Dimensions in parentheses are in millimeters and are derived form the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3}) inch).

Figure 11. Dimensions and Pad Layout



PACKAGE OPTION ADDENDUM

10-Dec-2020

PACKAGING INFORMATION

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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD4504BMPWREP	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	4504BEP	Samples
V62/09606-01XE	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	4504BEP	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

10-Dec-2020

OTHER QUALIFIED VERSIONS OF CD4504B-EP:

• Military: CD4504B-MIL

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

www.ti.com 3-Jun-2022

TAPE AND REEL INFORMATION



TAPE DIMENSIONS WHO WE PI WHO WE PI WHO WE BO WE Cavity A O WE Cavity

A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4504BMPWREP	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
I	CD4504BMPWREP	TSSOP	PW	16	2000	356.0	356.0	35.0	



SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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